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View Online at https://aerobasegroup.com/nsn/5961-01-338-5496 **Inclosure Material:** Glass **Overall Length:** Between 20.07 millimeters and 20.32 millimeters **Terminal Length:** Between 13.46 millimeters and 28.48 millimeters **Overall Height:** Between 6.32 millimeters and 6.60 millimeters **Overall Width:** Between 13.59 millimeters and 13.84 millimeters **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Mounting Method:** Terminal and unthreaded hole **Features Provided:** Hermetically sealed case and electrostatic sensitive **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 gate to source voltage **Current Rating Per Characteristic:** 24.00 amperes drain current **Power Rating Per Characteristic:** 125.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Nuclear hardness critical item **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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